Preferred Device

Triacs

Silicon Bidirectional Thyristors

Designed for high performance full-wave ac control applications where high noise immunity and high commutating di/dt are required.

- Blocking Voltage to 800 Volts
- On-State Current Rating of 8.0 Amperes RMS at 100°C
- Uniform Gate Trigger Currents in Three Quadrants
- High Immunity to dv/dt 250 V/µs minimum at 125°C
- Minimizes Snubber Networks for Protection
- Industry Standard TO-220AB Package
- High Commutating di/dt 6.5 A/ms minimum at 125°C
- Device Marking: Logo, Device Type, e.g., MAC8D, Date Code

Rating	Symbol	Value	Unit
Peak Repetitive Off–State Voltage ⁽¹⁾ (T _J = -40 to 125°C, Sine Wave, 50 to 60 Hz, Gate Open)	V _{DRM,} V _{RRM}		Volts
MAC8D MAC8M MAC8N		400 600 800	
On-State RMS Current (Full Cycle Sine Wave, 60 Hz, T _C = 100°C)	^I T(RMS)	8.0	Amps
Peak Non-Repetitive Surge Current (One Full Cycle Sine Wave, 60 Hz, T _J = 125°C)	ITSM	80	Amps
Circuit Fusing Consideration (t = 8.3 ms)	l ² t	26	A ² sec
Peak Gate Power (Pulse Width \leq 1.0 μ s, T _C = 80°C)	PGM	16	Watts
Average Gate Power (t = 8.3 ms, $T_C = 80^{\circ}C$)	PG(AV)	0.35	Watt
Operating Junction Temperature Range	Тj	-40 to +125	°C
Storage Temperature Range	T _{stg}	-40 to +150	°C

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

(1) V_{DRM} and V_{RRM} for all types can be applied on a continuous basis. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

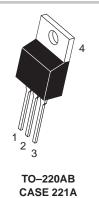


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TRIACS 8 AMPERES RMS 400 thru 800 VOLTS





CASE 221A STYLE 4

PIN ASSIGNMENT			
1	Main Terminal 1		
2	Main Terminal 2		
3	Gate		
4	Main Terminal 2		

ORDERING INFORMATION

Device	Package	Shipping
MAC8D	TO220AB	50 Units/Rail
MAC8M	TO220AB	50 Units/Rail
MAC8N	TO220AB	50 Units/Rail

Preferred devices are recommended choices for future use and best overall value.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance — Junction to Case — Junction to Ambient	R _θ JC R _{θJA}	2.2 62.5	°C/W
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds	тլ	260	°C

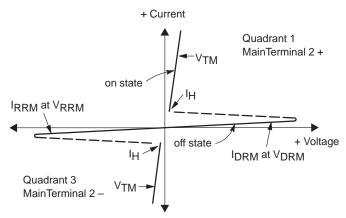
ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}C$ unless otherwise noted; Electricals apply in both directions)

Characteristic	Symbol	Min	Тур	Мах	Unit
OFF CHARACTERISTICS					•
Peak Repetitive Blocking Current $(V_D = Rated V_{DRM}, V_{RRM}; Gate Open)$ $T_J = 25^{\circ}C$ $T_J = 125^{\circ}C$	I _{DRM} , I _{RRM}			0.01 2.0	mA
ON CHARACTERISTICS		-		-	
Peak On-State Voltage* (I _{TM} = ±11 A Peak)	V _{TM}	_	1.2	1.6	Volts
Gate Trigger Current (Continuous dc) ($V_D = 12 V$, $R_L = 100 \Omega$) MT2(+), G(+) MT2(+), G(-) MT2(-), G(-)	IGT	5.0 5.0 5.0	13 16 18	35 35 35	mA
Holding Current ($V_D = 12 V$, Gate Open, Initiating Current = ±150 mA)	Чн	—	20	40	mA
Latching Current (V _D = 24 V, I _G = 35 mA) MT2(+), G(+); MT2(-), G(-) MT2(+), G(-)	ι		20 30	50 80	mA
Gate Trigger Voltage (V _D = 12 V, R _L = 100 Ω) MT2(+), G(+) MT2(+), G(-) MT2(-), G(-)	VGT	0.5 0.5 0.5	0.69 0.77 0.72	1.5 1.5 1.5	Volts
Gate Non–Trigger Voltage (V _D = 12 V, R _L = 100 Ω, T _J = 125°C) MT2(+), G(+); MT2(+), G(-); MT2(-), G(-)	V _{GD}	0.2	_	_	Volts
DYNAMIC CHARACTERISTICS		-		-	
Rate of Change of Commutating Current See Figure 10. (V _D = 400 V, I _{TM} = 4.4 A, Commutating dv/dt = 18 V/ μ s, Gate Open, T _J = 125°C, f = 250 Hz, No Snubber) C _L = 10 μ F L _L = 40 mH	(di/dt) _C	6.5	_	_	A/ms
Critical Rate of Rise of Off-State Voltage (V_D = Rated V_{DRM} , Exponential Waveform, Gate Open, T_J = 125°C)	dv/dt	250	-	_	V/µs

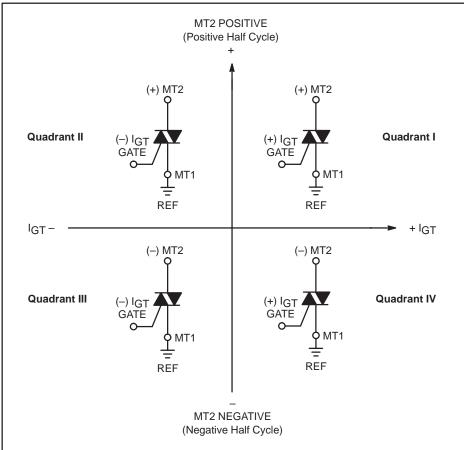
*Indicates Pulse Test: Pulse Width \leq 2.0 ms, Duty Cycle \leq 2%.

Voltage Current Characteristic of Triacs (Bidirectional Device)

Symbol	Parameter
VDRM	Peak Repetitive Forward Off State Voltage
IDRM	Peak Forward Blocking Current
VRRM	Peak Repetitive Reverse Off State Voltage
IRRM	Peak Reverse Blocking Current
VTM	Maximum On State Voltage
Ι _Η	Holding Current

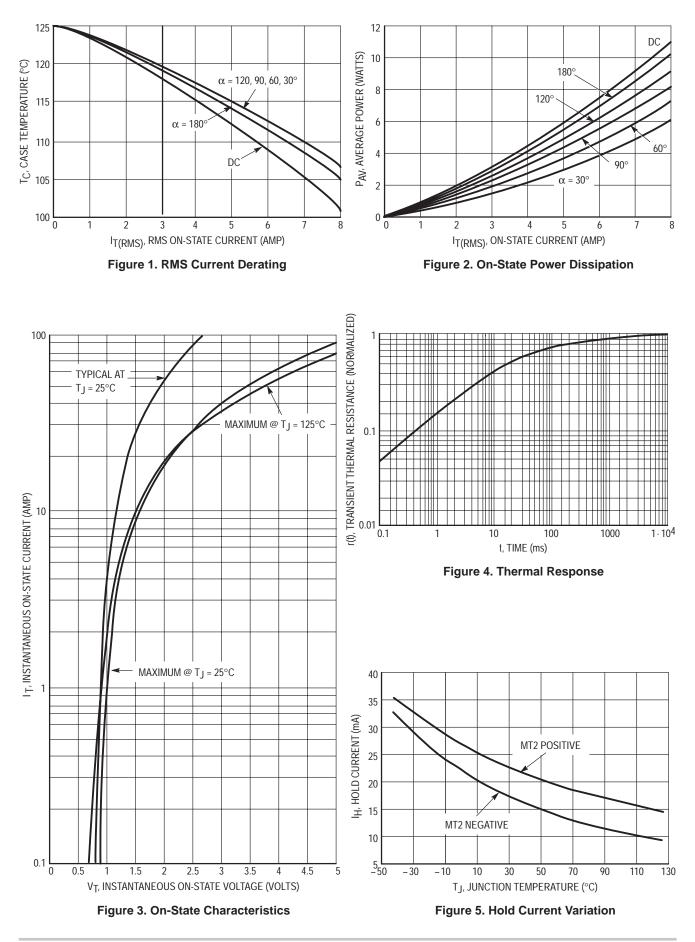


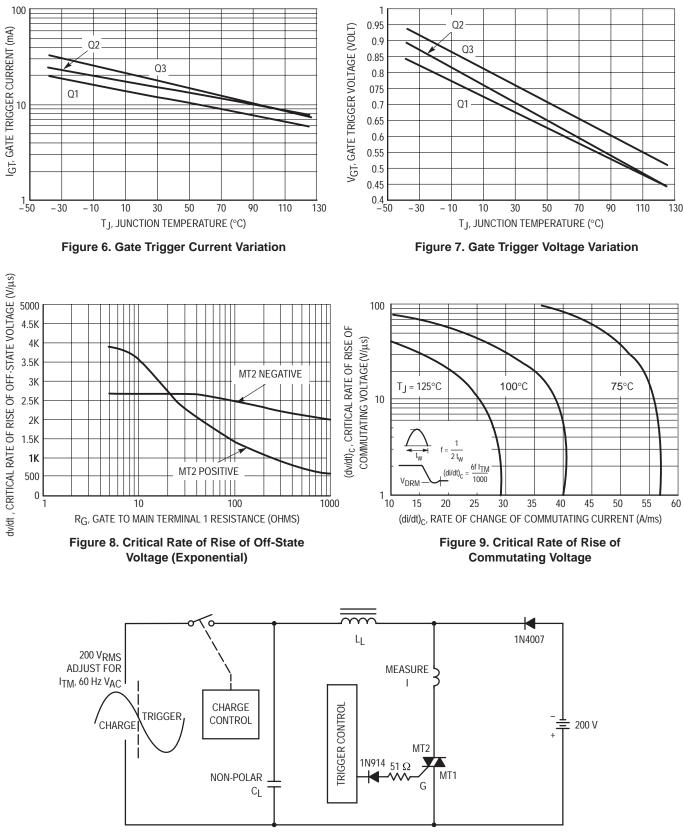




All polarities are referenced to MT1.

With in-phase signals (using standard AC lines) quadrants I and III are used.



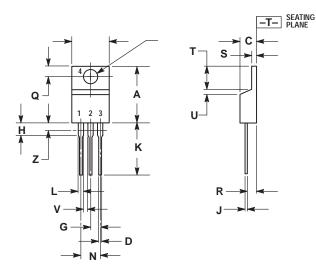


Note: Component values are for verification of rated (di/dt)_c. See AN1048 for additional information.



PACKAGE DIMENSIONS

TO-220AB CASE 221A-09 **ISSUE Z**



NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
С	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
Н	0.110	0.155	2.80	3.93
J	0.018	0.025	0.46	0.64
Κ	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
Ν	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
Т	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
V	0.045		1.15	
Ζ		0.080		2.04

STYLE 4: PIN 1. MAIN TERMINAL 1 2. MAIN TERMINAL 2 3. GATE 4. MAIN TERMINAL 2

Notes

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